

# VFJA100

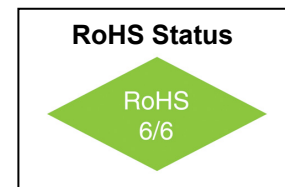
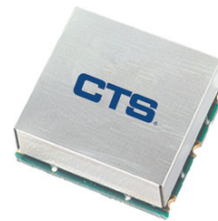
## Jitter Attenuator to 1GHz

### 25.4x22mm SMD, PECL/LVPECL



#### Features

- 1.0 GHz output frequency range
- Ultra low jitter: <0.2ps
- Meets OC-192 jitter transfer, generation and tolerance
- Low power: <220mW typical
- Low profile SMD package
- Compliant with Telcordia GR-1244-CORE, GR-253-CORE, ITU-T G.813, and ITU-T G.8261



#### Applications

- Sonet / SDH / ATM
- 10 Gigabit Ethernet
- Forward Error Correction (FEC)

#### Description

The **VFJA100** is a Jitter Attenuator capable of providing an output frequency up to 1GHz. An internal synthesizer locks to the input reference clock and multiplies it up to the desired output frequency. An internal voltage regulator offers improved stability and noise performance. The output is configured as a differential LVPECL signal and requires external termination resistors. The **VFJA100** is available in a 25.4mm x 22mm surface mount package.

#### Electrical Specifications

Parameter	Symbol	Condition	Min	Typ	Max	Unit	Note
Input Frequency	$F_{REF}$		0.008		100	MHz	Note 2
Output Frequency	$F_{OUT}$		50		1000	MHz	
Operating Temperature Range	T		0 -40		70 +85	°C	Order Code B Order Code G
Output		Signal	PECL / LVPECL				
Supply Voltage	$V_{CC}$		3.15	3.30	3.45	V	
Jitter		12kHz to 20MHz		0.2	0.8	ps	
SSB Phase Noise		100Hz 1kHz 10kHz 100kHz		-90 -118 -142 -145		dBc/Hz	@ 622.08MHz

#### Notes:

1. Consult factory for Bandwidth and Lock Range options
2. For  $F_{in} < 20$  MHz, ensure  $SR > 50$  V/ $\mu$ s

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**Electrical Specifications**

Parameter	Symbol	Condition	Min	Typ	Max	Unit	Note
Supply Current	$I_{CC}$	50 Ohms Load		62	75	mA	
Load	50 Ohms to $V_{CC}-2V$ or Thevenin Equivalent						
Duty Cycle		@ 50%	45	50	55	%	
Logic "1" Level	$V_{OH}$		$V_{CC}-0.96$		$V_{CC}-0.81$	V	
Logic "0" Level	$V_{OL}$		$V_{CC}-1.85$		$V_{CC}-1.65$	V	
Lock Range			20			ppm	Note 1
Input Level		AC Coupled Internally	1.0		3.3	$V_{P-P}$	
Enable / Disable Function	Input HIGH (>2.5V): DISABLED Input LOW (<0.5V) or floating: ACTIVE					LVCMOS	
Enable / Disable Time	$T_E/T_D$				100	ns	

**Absolute Maximum Ratings**

Parameter	Symbol	Condition	Min	Typ	Max	Unit	Note
Supply Voltage	$V_{CC}$		-0.5		+5.5	V	
Storage Temperature	$T_S$		-55		+105°	°C	

**How to Order**



**Temperature Range**

Code	Specification
B	0°C to +70°C
G	-40°C to +85°C

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**Environmental and Mechanical Conditions**

Parameter	Condition
<b>Mechanical Shock</b>	Per MIL-STD-202, Method 213, Condition E
<b>Thermal Shock</b>	Per MIL-STD-883, Method 1011, Condition A
<b>Vibration</b>	Per MIL-STD-883, Method 2007, Condition A
<b>Soldering Conditions</b>	260°C for 10s max
<b>Hermetic Seal</b>	Leak rate less than $5 \times 10^{-8}$ atm.cc/s of helium (crystal only)

